

XN02212 (XN2212)

Silicon NPN epitaxial planer transistor

For switching/digital circuits

■ Features

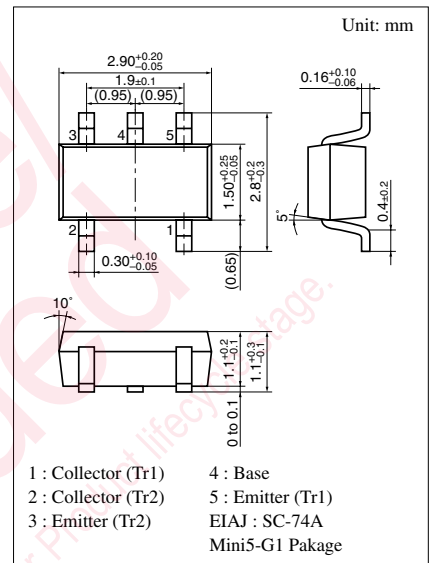
- Two elements incorporated into one package.
(Base-coupled transistors with built-in resistor)
- Reduction of the mounting area and assembly cost by one half.

■ Basic Part Number of Element

- UNR1212(UN1212) × 2 elements

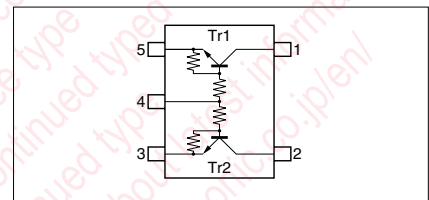
■ Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Ratings	Unit
Rating of element	Collector to base voltage	V_{CBO}	50 V
	Collector to emitter voltage	V_{CEO}	50 V
	Collector current	I_C	100 mA
Overall	Total power dissipation	P_T	300 mW
	Junction temperature	T_j	150 °C
	Storage temperature	T_{stg}	-55 to +150 °C



Marking Symbol: AX

Internal Connection



■ Electrical Characteristics (Ta=25°C)

Parameter	Symbol	Conditions	min	typ	max	Unit
Collector to base voltage	V_{CBO}	$I_C = 10\mu A, I_E = 0$	50			V
Collector to emitter voltage	V_{CEO}	$I_C = 2mA, I_B = 0$	50			V
Collector cutoff current	I_{CBO}	$V_{CB} = 50V, I_E = 0$			0.1	μA
	I_{CEO}	$V_{CE} = 50V, I_B = 0$			0.5	μA
Emitter cutoff current	I_{EBO}	$V_{EB} = 6V, I_C = 0$			0.5	mA
Forward current transfer ratio	h_{FE}	$V_{CE} = 10V, I_C = 5mA$	60			
Forward current transfer h_{FE} ratio	$h_{FE}(\text{small/large})^{*1}$	$V_{CE} = 10V, I_C = 5mA$	0.5	0.99		
Collector to emitter saturation voltage	$V_{CE(\text{sat})}$	$I_C = 10mA, I_B = 0.3mA$			0.25	V
Output voltage high level	V_{OH}	$V_{CC} = 5V, V_B = 0.5V, R_L = 1k\Omega$	4.9			V
Output voltage low level	V_{OL}	$V_{CC} = 5V, V_B = 2.5V, R_L = 1k\Omega$			0.2	V
Transition frequency	f_T	$V_{CB} = 10V, I_E = -2mA, f = 200MHz$		150		MHz
Input resistance	R_1		-30%	22	+30%	k Ω
Resistance ratio	R_1/R_2		0.8	1.0	1.2	

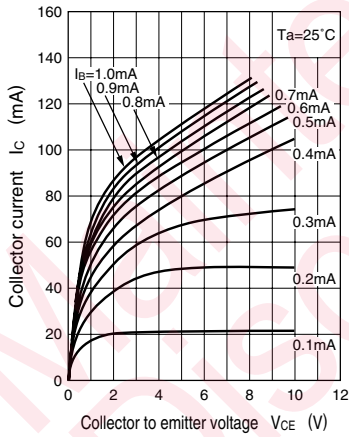
*1 Ratio between 2 elements

Note) The Part number in the Parenthesis shows conventional part number.

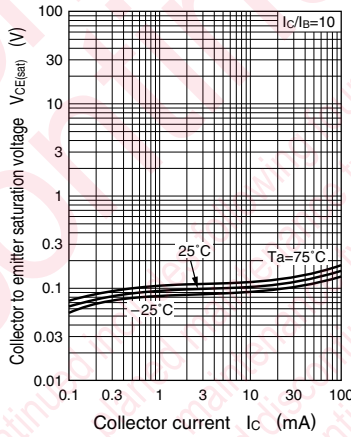
$P_T - T_a$



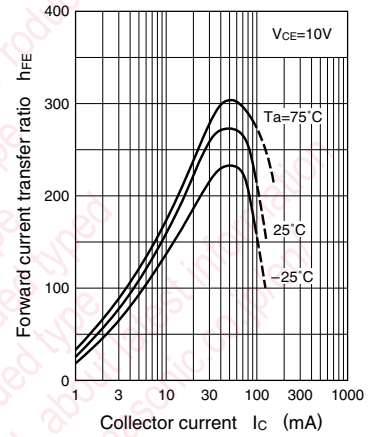
$I_C - V_{CE}$



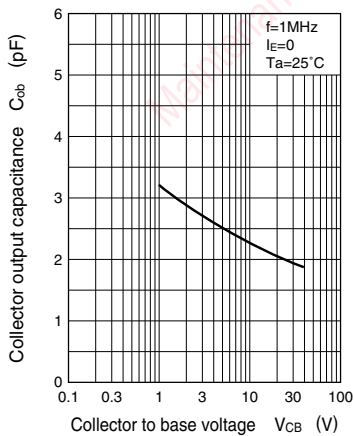
$V_{CE(sat)} - I_C$



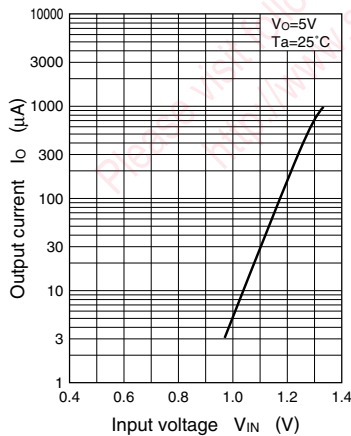
$h_{FE} - I_C$



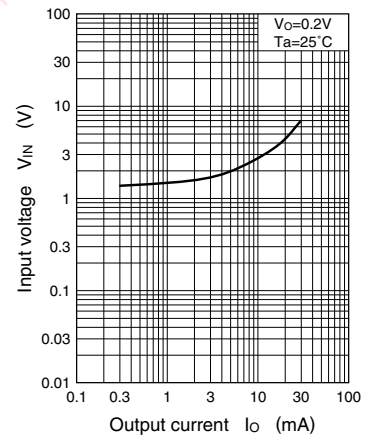
$C_{ob} - V_{CB}$



$I_O - V_{IN}$



$V_{IN} - I_O$



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